TOSHIBA FIELD EFFECT TRANSISTOR SILICON N CHANNEL MOS TYPE

# 2SK1739A

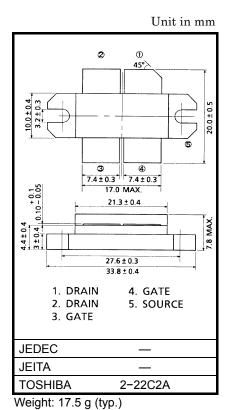
RF Power MOS FET for UHF TV Broadcast Transmitter

- Output Power  $: Po \ge 90 W (min.)$ •
- Drain Efficiency
- Frequency
- $: \eta_{\rm D} = 50\%$  (typ.)
- : f = 770 MHz
- Push–Pull Structure Package

### Absolute Maximum Ratings (Tc = 25°C)

| CHARACTERISTIC            | SYMBOL           | RATING  | UNIT |
|---------------------------|------------------|---------|------|
| Drain-Source Voltage      | V <sub>DSS</sub> | 80      | V    |
| Gate-Source Voltage       | V <sub>GSS</sub> | ±20     | V    |
| Drain Current             | ۱ <sub>D</sub>   | 11      | А    |
| Reverse Drain Current     | I <sub>DR</sub>  | 11      | А    |
| Drain Power Dissipation   | PD               | 250     | W    |
| Channel Temperature       | T <sub>ch</sub>  | 150     | °C   |
| Storage Temperature Range | T <sub>stg</sub> | -55~150 | °C   |

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in



temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

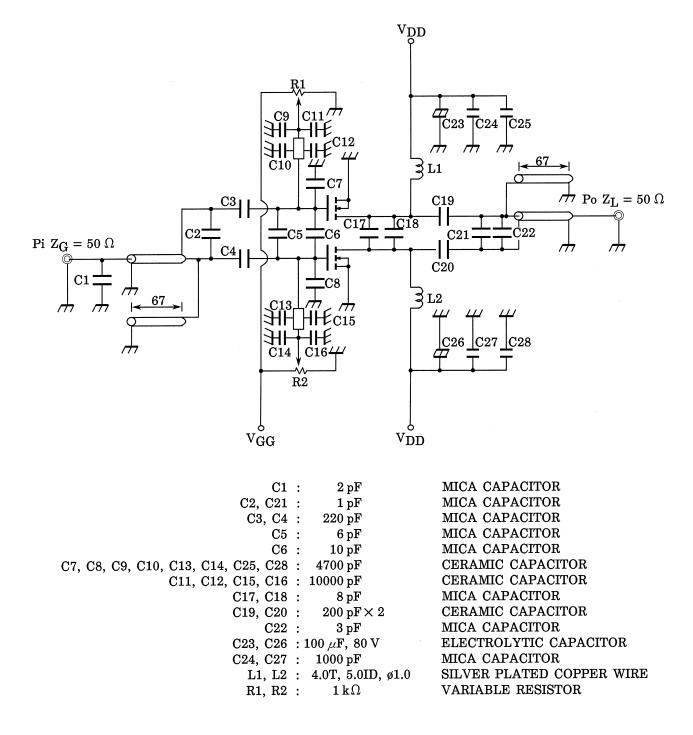
Electrical Characteristics (Tc = 25°C)

| CHARACTERISTIC                 | SYMBOL               | TEST CONDITION   | MIN. | TYP. | MAX. | UNIT |
|--------------------------------|----------------------|--|------|------|------|------|
| Output Power                   | Po                   | V <sub>DD</sub> = 40 V, lidle = 0.2 A × 2              | 90   | 110  | _    | W    |
| Drain Efficiency               | ηD                   | Pi = 10 W, f = 770 MHz *                               | _    | 50   | _    | %    |
| Drain-Source Breakdown Voltage | V (BR) DSS           | I <sub>D</sub> = 5 mA, V <sub>GS</sub> = 0             | 80   | _    | _    | V    |
| Drain Cut-off Current          | I <sub>DSS</sub>     | V <sub>DS</sub> = 60 V, V <sub>GS</sub> = 0            | _    | _    | 1.0  | mA   |
| Gate Threshold Voltage         | V <sub>th</sub>      | I <sub>D</sub> = 0.5 mA, V <sub>DS</sub> = 10 V        | 0.5  | _    | 3.0  | V    |
| Drain-Source ON Resistance     | R <sub>DS (on)</sub> | I <sub>D</sub> = 2 A, V <sub>GS</sub> = 10 V **        | _    | 0.5  | 1.5  | Ω    |
| Drain-Source ON Voltage        | V <sub>DS (on)</sub> | I <sub>D</sub> = 2 A, V <sub>GS</sub> = 10 V **        | _    | 1.0  | 3.0  | V    |
| Forward Transfer Admittance    | Y <sub>fs</sub>      | I <sub>D</sub> = 1.5 A, V <sub>DS</sub> = 20 V **      | 0.9  | 1.3  | _    | S    |
| Input Capacitance              | C <sub>iss</sub>     | V <sub>DS</sub> = 40 V, V <sub>GS</sub> = 0, f = 1 MHz | _    | 80   | _    | pF   |
| Output Capacitance             | C <sub>oss</sub>     | V <sub>DS</sub> = 40 V, V <sub>GS</sub> = 0, f = 1 MHz | _    | 40   | _    | pF   |
| Reverse Transfer Capacitance   | C <sub>rss</sub>     | V <sub>DS</sub> = 40 V, V <sub>GS</sub> = 0, f = 1 MHz | _    | 1    | _    | pF   |

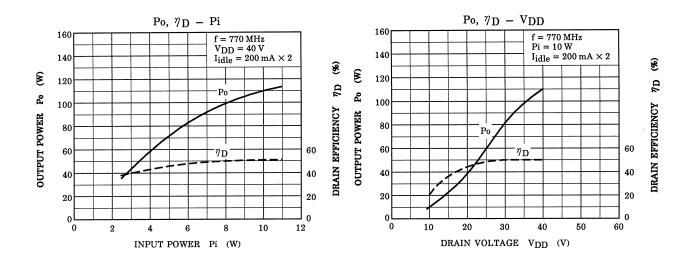
\*: Push-Pull Operation \*\*: Pulse Test

This transistor is the electrostatic sensitive device. Please handle with caution.

### **RF Output Power Test Fixture**



## TOSHIBA



#### Caution

These are only typical curves and devices are not necessarily guaranteed at these curves.

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